Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material: | |
|---|-------|
| Metal | |
| Overall Length: | |
| 1.000 inches | |
| Overall Height: | |
| Between 1.719 inches and 1.781 inches | |
| Overall Width: | |
| 1.000 inches | |
| Mounting Facility Quantity: | |
| 1 | |
| Mounting Method: | |
| Threaded stud | |
| Thready Qty Per Inch (tpi): | |
| 32 | |
| Thread Size: | |
| 0.312 inches | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| 264.0 forward voltage, total rms | |
| Current Rating Per Characteristic: | |
| 5.50 amperes collector current, dc outside diameter | |
| Maximum Operating Tempurature Per Measurement Pe | oint: |
| 85.0 degrees celsius junction | |
| Thread Series Designator: | |
| Unf | |
| Terminal Type And Quantity: | |
| 2 uninsulated wire lead w/terminal lug | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |